

The GreenMOS<sup>®</sup> high voltage MOSFET utilizes charge balance technology to achieve outstanding low on-resistance and lower gate charge. It is engineered to minimize conduction loss, provide superior switching performance and robust avalanche capability.

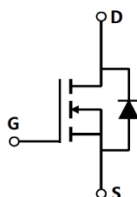
GreenMOS<sup>®</sup>



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Parameter	Value	Unit
$V_{DS, min} @ T_{j(max)}$	700	V
$I_{D, pulse}$	15	A
$R_{DS(ON), max} @ V_{GS}=10V$	900	
$Q_g$	9.0	nC

Product Name	Package	Marking
OSG65R900DEF	TO252	OSG65R900DE



**Absolute Maximum Ratings** at  $T_j=25$  unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-source voltage	$V_{DS}$	650	V
Gate-source voltage	$V_{GS}$	$\pm 30$	V
Continuous drain current <sup>1)</sup> , $T_C=25$ °C	$I_D$	5	A
Continuous drain current <sup>1)</sup> , $T_C=100$ °C		3.2	
Pulsed drain current <sup>2)</sup> , $T_C=25$ °C	$I_{D, pulse}$	15	A
Continuous diode forward current <sup>1)</sup> , $T_C=25$ °C	$I_S$	5	A
Diode pulsed current <sup>2)</sup> , $T_C=25$ °C	$I_{S, pulse}$	15	A
Power dissipation <sup>3)</sup> , $T_C=25$ °C	$P_D$	37	W
Single pulsed avalanche energy <sup>5)</sup>	$E_{AS}$	130	mJ
MOSFET dv/dt ruggedness, $V_{DS}$	dv/dt	50	V/ns
Reverse diode dv/dt, $V_{DS}$	dv/dt	15	V/ns
Operation and storage temperature	$T_{stg}, T_j$	-55 to 150	°C

**Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal resistance, junction-case	R	3.4	°C/W
Thermal resistance, junction-ambient <sup>4)</sup>	R	62	°C/W

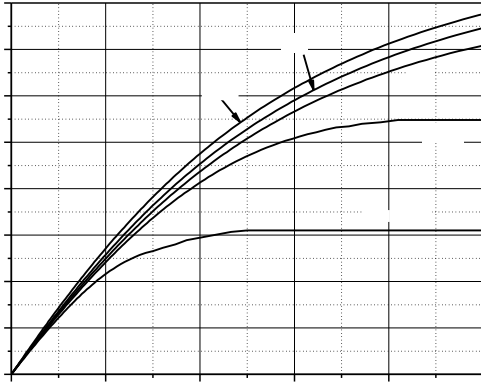
**Electrical Characteristics** at  $T_j=25$  unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Drain-source breakdown voltage	$BV_{DSS}$	650			V	$V_{GS}=0$ V, $I_D=250$ A
		700	770			$V_{GS}=0$ V, $I_D$ , $T_j=150$ °C
Gate threshold voltage	$V_{GS(th)}$	2.9		3.9	V	$V_{DS}=V_{GS}$ , $I_D=250$ A
Drain-source on-state resistance	$R_{DS(ON)}$		0.8	0.9		$V_{GS}=10$ V, $I_D=2.5$ A
			2.3			$V_{GS}=10$ V, $I_D=2.5$ A, $T_j=150$ °C
Gate-source leakage current	$I_{GSS}$			100	nA	$V_{GS}=30$ V
				-100		$V_{GS}=-30$ V
Drain-source leakage current	$I_{DSS}$			1	A	$V_{DS}=650$ V, $V_{GS}=0$ V

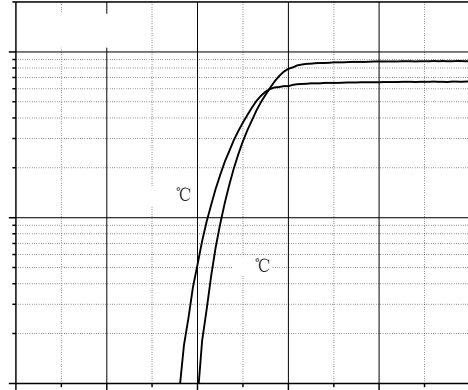
**Dynamic Characteristics**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Input capacitance	$C_{iss}$		408.0		pF	$V_{GS}=0\text{ V}$ , $V_{DS}=50\text{ V}$ , Hz
Output capacitance	$C_{oss}$		30.3		pF	
Reverse transfer capacitance	$C_{rss}$		1.4		pF	
Turn-on delay time	$t_{d(on)}$		27.4		ns	$V_{GS}=10\text{ V}$ , $V_{DS}=400\text{ V}$ , $R_G=2$ $I_D=2.5\text{ A}$
Rise time	$t_r$		12.6		ns	
Turn-off delay time	$t_{d(off)}$					

**Electrical Characteristics Diagrams**



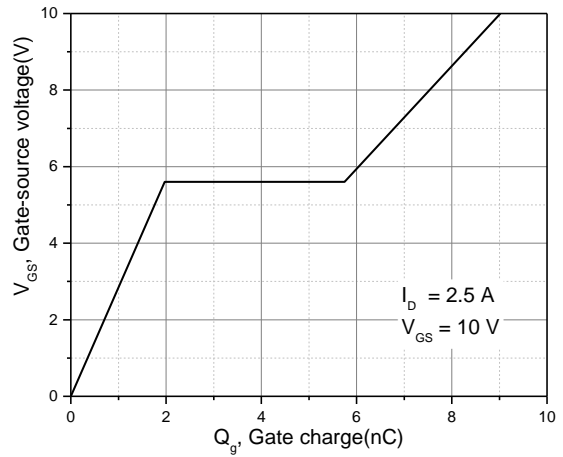
**Figure 1. Typ. output characteristics**



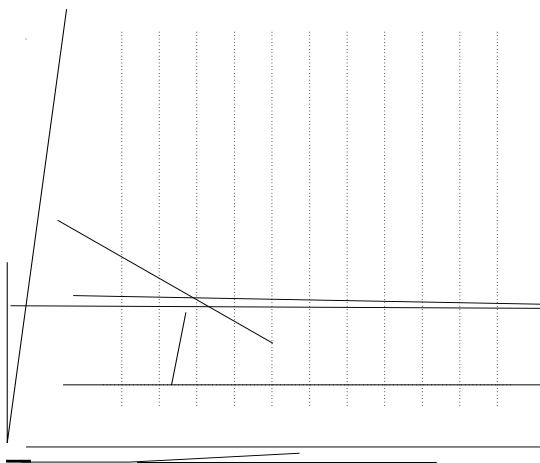
**Figure 2. Typ. transfer characteristics**



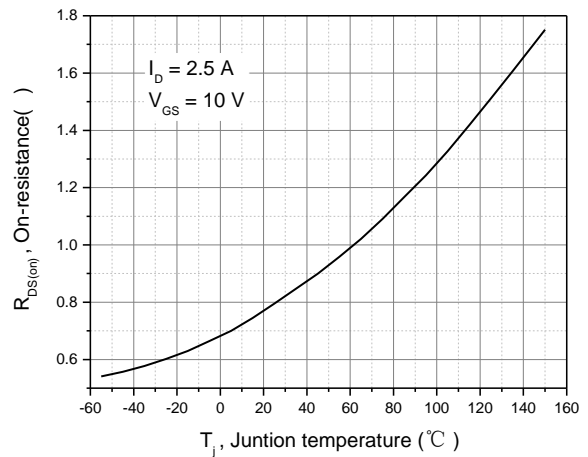
**Figure 3. Typ. capacitances**



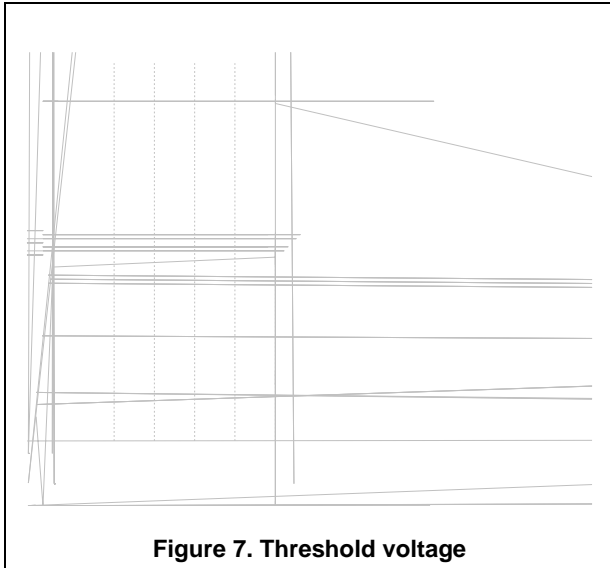
**Figure 4. Typ. gate charge**



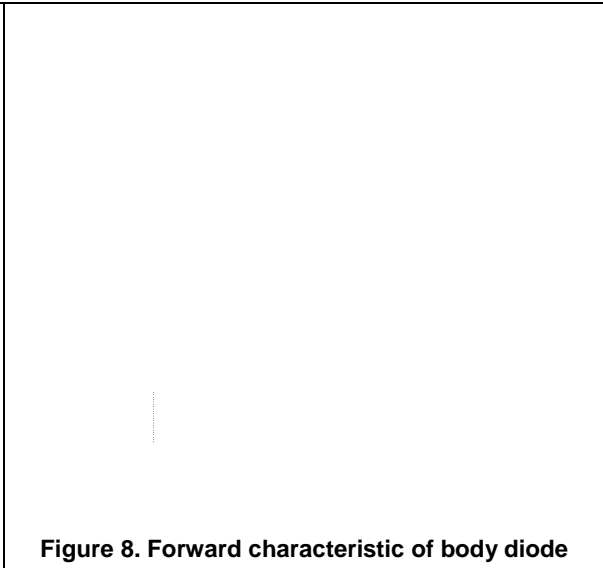
**Figure 5. Drain-source breakdown voltage**



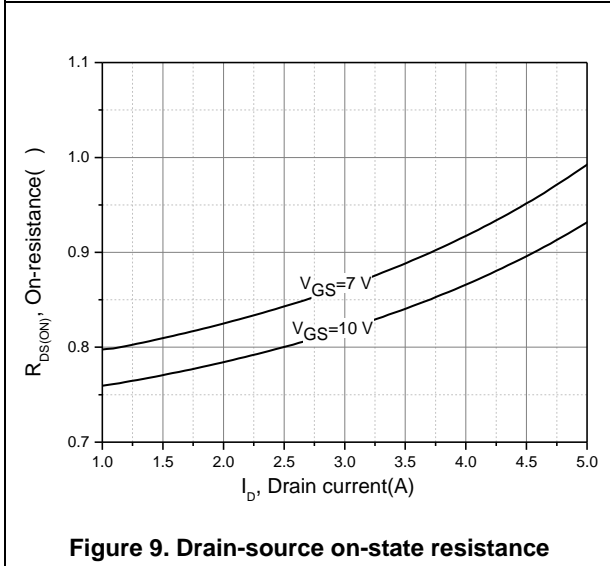
**Figure 6. Drain-source on-state resistance**



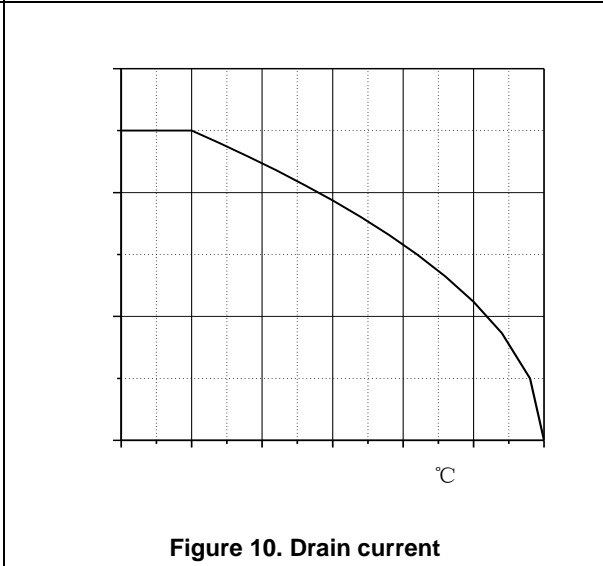
**Figure 7. Threshold voltage**



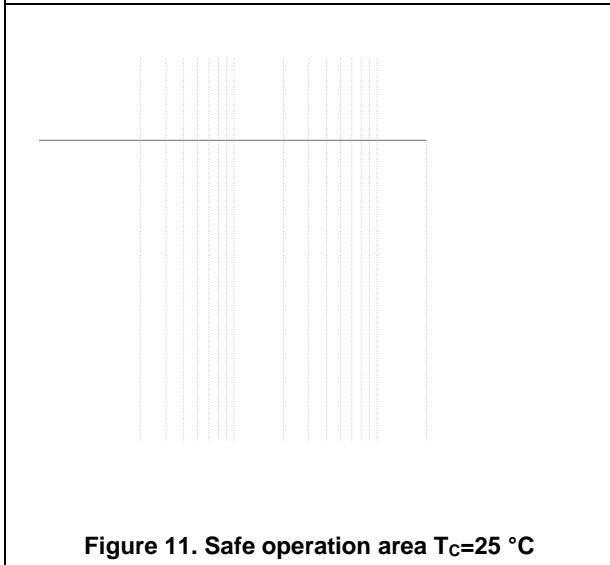
**Figure 8. Forward characteristic of body diode**



**Figure 9. Drain-source on-state resistance**

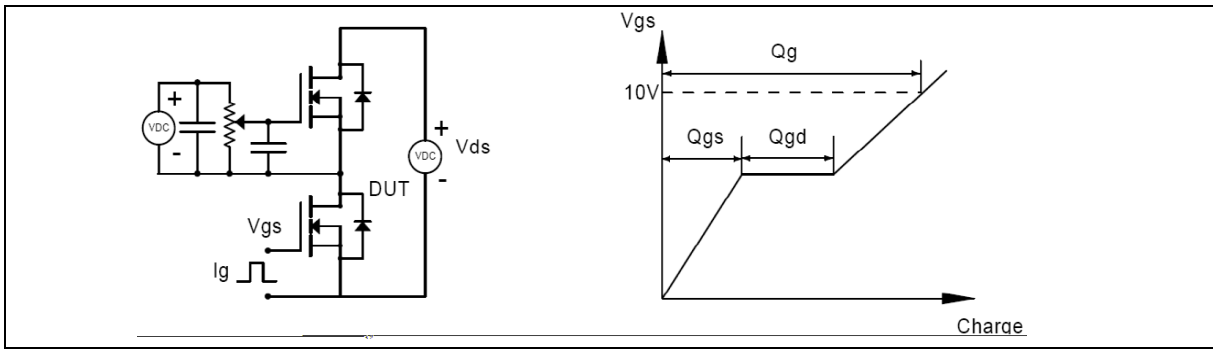


**Figure 10. Drain current**



**Figure 11. Safe operation area  $T_C=25^{\circ}C$**

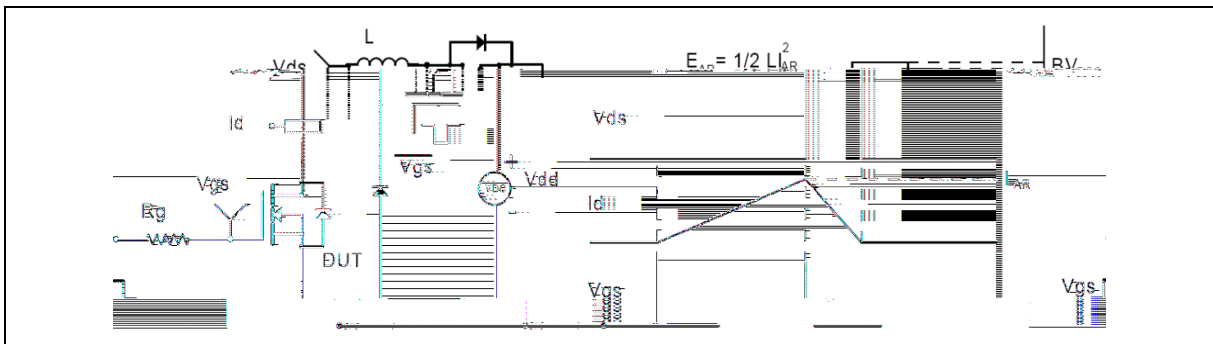
**Test circuits and waveforms**



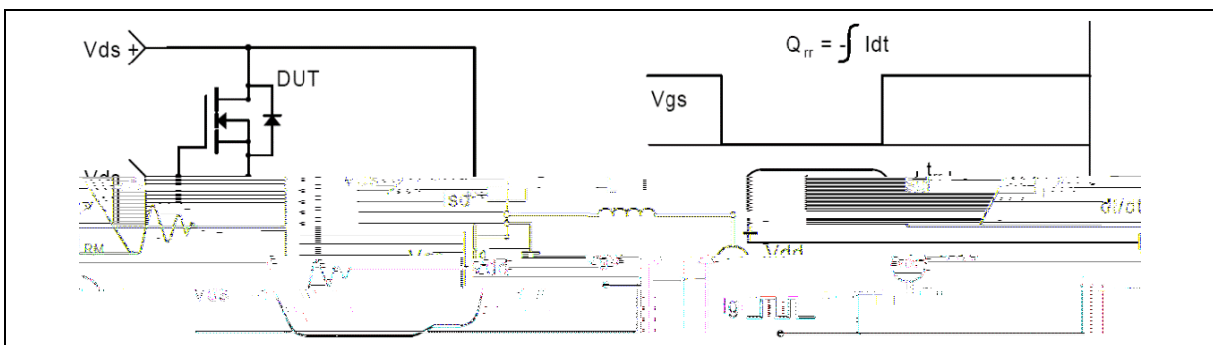
**Figure 1. Gate charge test circuit & waveform**



**Figure 2. Switching time test circuit & waveforms**



**Figure 3. Unclamped inductive switching (UIS) test circuit & waveforms**

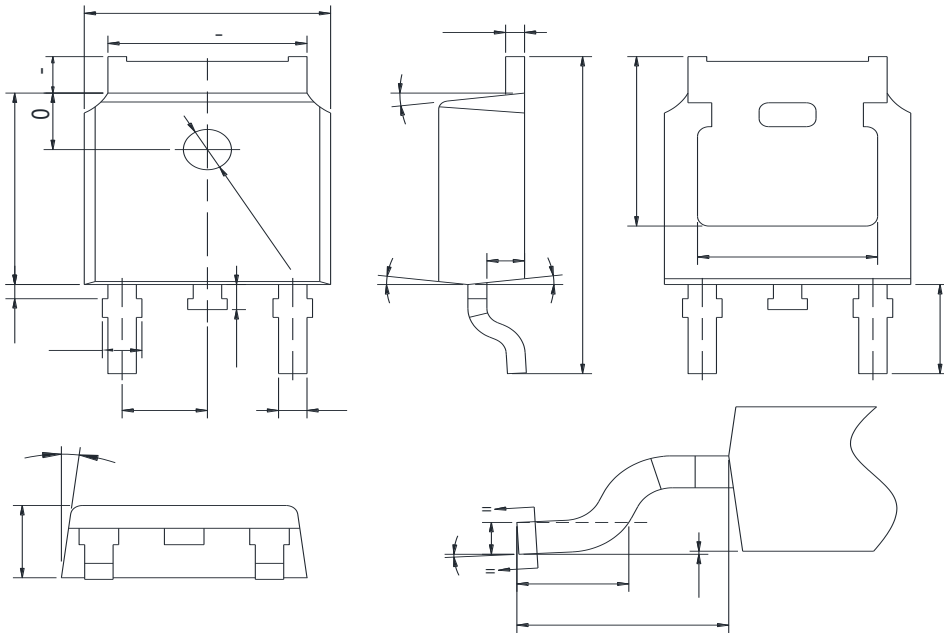


**Figure 4. Diode reverse recovery test circuit & waveforms**

## Package Information

Symbol	mm
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**Package Information**



Symbol	mm		
	Min	Nom	Max
A	2.20	2.30	2.38
A1	0.00	-	0.10
A2	0.90	1.01	1.10
b	0.72	-	0.85
b1	0.71	0.76	0.81
b2	0.72	-	0.90
b3	5.13	5.33	5.46
c	0.47	-	0.60
c1	0.46	0.51	0.56
c2	0.47	-	0.60
D	6.00	6.10	6.20
D1	5.25	-	-
E	6.50	6.60	6.70
E1	4.70	-	-
e	2.186	2.286	2.386
H	9.80	10.10	10.40
L	1.40	1.50	1.70
L1	2.90REF		
L2	0.508BSC		
L3	0.90	-	1.25
L4	0.60	0.80	1.00
L5	0.15	-	0.75
L6	1.80REF		
	0	-	

Version 2: TO252-J package outline dimension



**Ordering Information**

Package Type	Units/ Reel	Reels/ Inner Box	Units/ Inner Box	Inner Boxes/ Carton Box	Units/ Carton Box
TO252-C	2500	2	5000	5	25000
TO252-J	2500	2	5000	5	25000

**Product Information**

Product	Package	Pb Free	RoHS	Halogen Free
OSG65R900DEF	TO252	yes	yes	yes